BAS86

Schottky barrier single diode

25 July 2012

Product data sheet

1. Product profile

1.1 General description

Planar Schottky barrier diode with an integrated guard ring for stress protection, encapsulated in a small hermetically sealed SOD80C glass Surface-Mounted Device (SMD) package with tin-plated metal discs at each end. It is suitable for "automatic placement" and as such it can withstand immersion soldering.

1.2 Features and benefits

- Low forward voltage
- High breakdown voltage
- Guard ring protected
- · Hermetically sealed glass SMD package.

1.3 Applications

- Ultra high-speed switching
- Voltage clamping
- Protection circuits
- · Blocking diodes

1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
I _{F(AV)}	average forward current		[1]	-	-	200	mA
V_R	reverse voltage			-	-	50	V
V _F	forward voltage	I _F = 100 mA; T _{amb} = 25 °C		-	-	900	mV

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.





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2. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode[1]	k a	к _} А
2	Α	anode	LLDS; MiniMelf (SOD80C)	aaa-003679

^[1] The marking band indicates the cathode.

3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
BAS86	LLDS; MiniMelf	hermetically sealed glass surface-mounted package; 2 connectors	SOD80C

4. Marking

Table 4. Marking codes

Type number	Marking code
BAS86	marking band

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V_R	reverse voltage			-	50	V
I _F	forward current			-	200	mA
I _{F(AV)}	average forward current		[1]	-	200	mA
I _{FRM}	repetitive peak forward current	$t_p \le 1 \text{ s}; \ \delta \le 0.5$		-	500	mA
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; $T_{j(init)}$ = 25 °C		-	5	А
Tj	junction temperature			-	125	°C
T _{amb}	ambient temperature			-65	125	°C
T _{stg}	storage temperature			-65	150	°C

^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

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6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	[1]	-	-	320	K/W

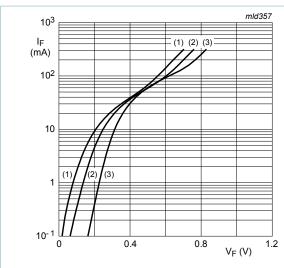
^[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

7. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _F	forward voltage	I _F = 0.1 mA; T _{amb} = 25 °C	-	-	300	mV
		I _F = 1 mA; T _{amb} = 25 °C	-	-	380	mV
		I _F = 10 mA; T _{amb} = 25 °C	-	-	450	mV
		I _F = 30 mA; T _{amb} = 25 °C	-	-	600	mV
		I _F = 100 mA; T _{amb} = 25 °C	-	-	900	mV
I _R	reverse current	V_R = 40 V; T_{amb} = 25 °C; pulsed; $t_p \le 300 \ \mu s$; $\delta \le 0.02$	-	-	5	μA
C _d	diode capacitance	f = 1 MHz; T _{amb} = 25 °C; V _R = 1 V	-	-	8	pF
t _{rr}	reverse recovery time	I_F = 10 mA; I_R = 10 mA; R_L = 100 Ω; $I_{R(meas)}$ = 1 mA; T_{amb} = 25 °C	-	-	4	ns

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- (1) T_{amb} = 125 °C
- (2) T_{amb} = 85 °C
- $(3) T_{amb} = 25 °C$

Fig. 1. Forward current as a function of forward voltage; typical values

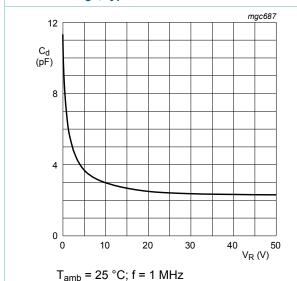
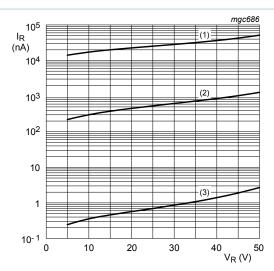
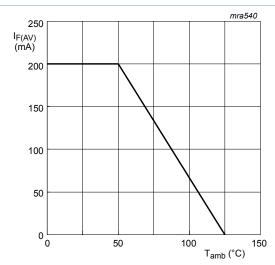


Fig. 3. Diode capacitance as a function of reverse voltage; typical values



- (1) $T_{amb} = 85 \, ^{\circ}C$
- (2) T_{amb} = 25 °C
- $(3) T_{amb} = -40 °C$

Fig. 2. Reverse current as a function of reverse voltage; typical values

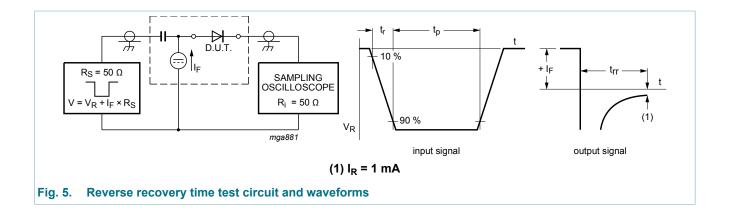


FR4 PCB, standard footprint

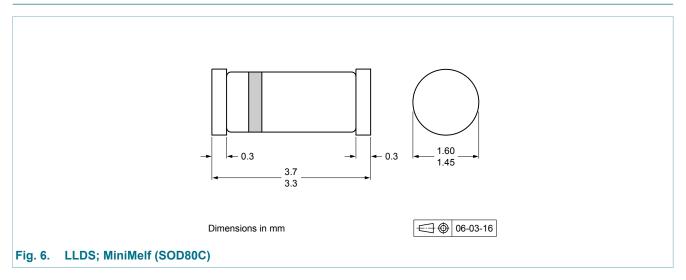
Fig. 4. Average forward current as a function of ambient temperature; derating curve

8. Test information

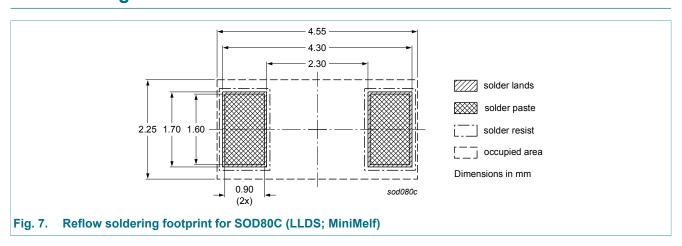
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9. Package outline



10. Soldering



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11. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
BAS86 v.5	20120725	Product data sheet	-	BAS86 v.4
Modifications:	Editorial update			,
BAS86 v.4	20100908	Product data sheet	-	BAS86 v.3
BAS86 v.3	20000525	Product specification	-	BAS86 v.2
BAS86 v.2	19961001	Product specification	-	BAS86 v.1
BAS86 v.1	19960320	Product specification	-	-

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12. Legal information

12.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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